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Vishay Semiconductors

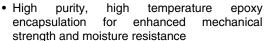
High Performance Schottky Rectifier, 2 x 7.5 A



PRIMARY CHARACTERISTICS								
I _{F(AV)}	2 x 7.5 A							
V_{R}	35 V, 45 V							
V _F at I _F	0.57 V							
I _{RM} max.	15 mA at 125 °C							
T _J max.	150 °C							
E _{AS}	7 mJ							
Package	TO-220AB 3L							
Circuit configuration	Common cathode							

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- · High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

DESCRIPTION

The VS-MBR15...CT... center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I _{F(AV)}	Rectangular waveform	15	А					
V _{RRM}		35/45	V					
I _{FSM}	$t_p = 5 \mu s sine$	690	Α					
V _F	7.5 A _{pk} , T _J = 125 °C	0.57	V					
T _J	Range	-65 to +150	°C					

VOLTAGE RATINGS							
PARAMETER SYMBOL VS-MBR1535CT-M3 VS-MBR1545CT-M3 UNITS							
Maximum DC reverse voltage	V_{R}	35	45	V			
Maximum working peak reverse voltage	V _{RWM}	35	45	V			

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS			
Maximum average forward per leg			T 101 % wated //		7.5	7.5		
current per device	I _{F(AV)}	$T_C = 131$ °C, rated V_R		15				
Maximum peak one cycle non-repetitive	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	690	А			
surge	1 GW	Surge applied at rated load condition half wave single phase 60 Hz		150				
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 3.5 mH		7	mJ			
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _{II} maximum V _A = 1.5 x V _R typical		2	А			



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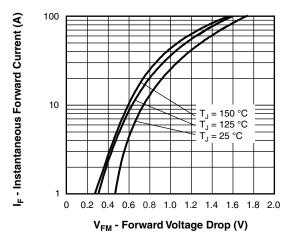
ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS				
		15 A	T _J = 25 °C	0.84	V			
Maximum forward voltage drop	V _{FM} ⁽¹⁾	7.5 A	T _{.1} = 125 °C	0.57				
		15 A	1j = 125 C	0.72				
Maximum instantaneous reverse current	I _{RM} ⁽¹⁾	T _J = 25 °C	Dated DC voltage	0.1	mA			
Maximum instantaneous reverse current		T _J = 125 °C	Rated DC voltage	15				
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal ran	400	pF				
Typical series inductance	L _S	Measured from top of term	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs				

Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction temperat	ure range	TJ		- 65 to 150	°C			
Maximum storage temperate	ure range	T _{Stg}		- 65 to 175				
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation	3.0				
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	°C/W			
Maximum thermal resistance, junction to ambient		R _{thJA}	DC operation	60				
Annyovimata waight				2	g			
Approximate weight				0.07	OZ.			
Mounting torque	minimum			6 (5)	kgf · cm			
Mounting torque	maximum				(lbf ⋅ in)			
Marking device			Coop obile TO 200AD 21	MBR1535CT				
			Case style TO-220AB 3L	MBR1	MBR1545CT			

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100 $T_1 = 150 \, ^{\circ}C$ I_R - Reverse Current (mA) 10 T₁ = 125 °C 0.1 0.01 0.00 0.0001 25 30 35 0 15 20 40 V_R - Reverse Voltage (V)

Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

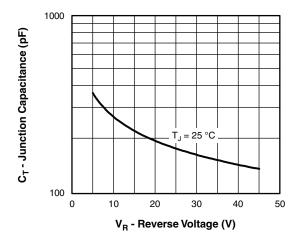


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

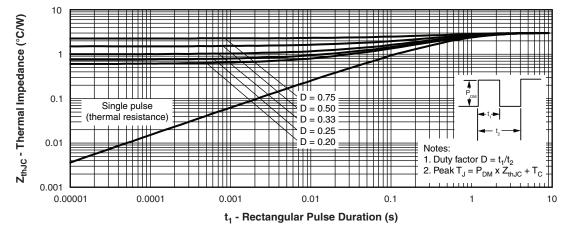


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

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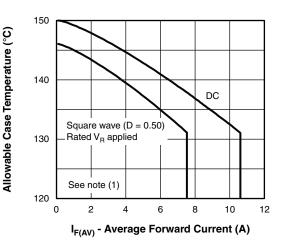


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

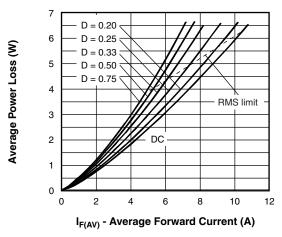


Fig. 6 - Forward Power Loss Characteristics

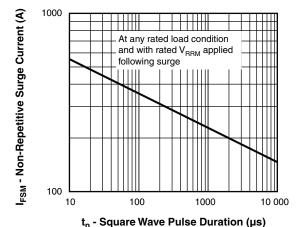


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

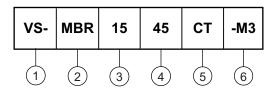
 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D)}; \ I_R \text{ at } V_{R1} = \text{rated } V_R \\ \end{array}$

VS-MBR1535CT-M3, VS-MBR1545CT-M3

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ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

2 - Schottky MBR series

Current rating (15 = 15 A)

- Voltage ratings 35 = 35 V 45 = 45 V

- CT = essential part number

6 - Environmental digit

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	PACKAGING DESCRIPTION							
VS-MBR1535CT-M3	50	Antistatic plastic tubes						
VS-MBR1545CT-M3	50	Antistatic plastic tubes						

LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?96154						
Part marking information	www.vishay.com/doc?95028						
SPICE model	www.vishay.com/doc?95294						



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TO-220AB 3L

DIMENSIONS in millimeters and inches





Conforms to JEDEC® outline TO-220AB

SYMBOL	MILLIM	IETERS	INCHES		NOTES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055			Е	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355								

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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